TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

## TC74HC4066AP,TC74HC4066AF,TC74HC4066AFT

#### **Quad Bilateral Switch**

The TC74HC4066A is a high speed CMOS QUAD BILATERAL SWITCH fabricated with silicon gate C<sup>2</sup>MOS technology.

It consists of four independent high speed switches capable of controlling either digital or analog signals while maintaining the CMOS low power dissipation.

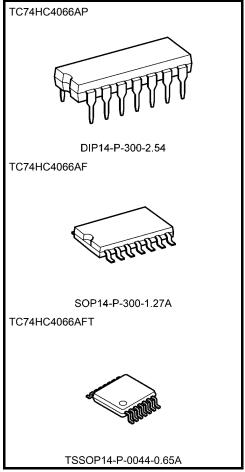
Control input (C) is provided to control the switch. The switch turns ON while the C input is high, and the switch turns OFF while low.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### **Features**

High speed:  $t_{pd}=7$  ns (typ.) at  $V_{CC}=5$  V Low power dissipation:  $I_{CC}=1$   $\mu A$  (max) at  $T_a=25$ °C High noise immunity:  $V_{NIH}=V_{NIL}=28\%$   $V_{CC}$  (min) Low ON resistance:  $R_{ON}=50$   $\Omega$  (typ.) at  $V_{CC}=9$  V High degree of linearity: THD = 0.05% (typ.) at  $V_{CC}=5$  V

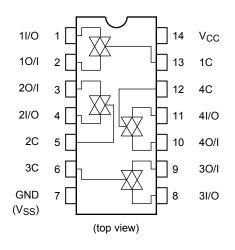
Pin and function compatible with 4066B



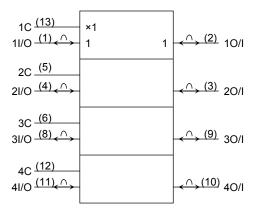
Weight

DIP14-P-300-2.54 : 0.96 g (typ.) SOP14-P-300-1.27A : 0.18 g (typ.) TSSOP14-P-0044-0.65A : 0.06 g (typ.)

# **Pin Assignment**



# **IEC Logic Symbol**



## **Truth Table**

Control	Switch Function
Н	On
L	Off



#### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	−0.5 to 13	V
Control input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Switch I/O voltage	V <sub>I/O</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Control input diode current	l <sub>IK</sub>	±20	mA
I/O diode current	lok	±20	mA
Switch through Current	lout	±25	mA
DC V <sub>CC</sub> /ground current	I <sub>CC</sub>	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T <sub>stg</sub>	−65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

#### **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2 to 12	V
Control input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V
Switch I/O voltage	V <sub>I/O</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	t <sub>r,</sub> t <sub>f</sub>	0 to 1000 (V <sub>CC</sub> = 2.0 V)	
		0 to 500 (V <sub>CC</sub> = 4.5 V)	ns
		0 to 400 (V <sub>CC</sub> = 6.0 V)	115
		0 to 250 (V <sub>CC</sub> = 10.0 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused control inputs must be tied to either VCC or GND.



## **Electrical Characteristics**

#### **DC Characteristics**

Characteristics Symbol		Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit	
Sharaetensiles	Cymbol	rest Gondidon	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Oint	
			2.0	1.50	_	_	1.50	_		
High-level control	V		4.5	3.15	_	_	3.15	_	V	
input voltage VIHC	VIHC	_		6.30	_	_	6.30	_	V	
				8.40	_	_	8.40	_		
			2.0	_	_	0.50	_	0.50		
Low-level control	$V_{ILC}$		4.5	_	_	1.35	_	1.35	V	
input voltage	VILC	_	9.0	_	_	2.70	_	2.70	V	
			12.0	_	_	3.60	_	3.60		
		V <sub>IN</sub> = V <sub>IHC</sub>	4.5	_	96	170	_	200		
		$V_{I/O} = V_{CC}$ to GND	9.0	_	55	85	_	100		
		I <sub>I/O</sub> ≤ 1 mA	12.0	_	45	80	_	90		
ON resistance	R <sub>ON</sub>	V <sub>IN</sub> = V <sub>IHC</sub>	2.0	_	160	_	_	_	Ω	
		V <sub>I/O</sub> = V <sub>CC</sub> or GND	4.5	_	70	100	_	130		
			9.0	_	50	75	_	95		
		I <sub>I/O</sub> ≤ 1 mA	12.0	_	45	70	_	90		
Difference of ON		V <sub>IN</sub> = V <sub>IHC</sub>	4.5	_	10	_	_	_		
resistance between	$\Delta R_{ON}$	$V_{I/O} = V_{CC}$ to GND	9.0	_	5	_	_	_	Ω	
switches		I <sub>I/O</sub> ≤ 1 mA		_	_					
Input/output leakage		$V_{OS} = V_{CC}$ or GND								
current	I <sub>OFF</sub>	$V_{IS}$ = GND or $V_{CC}$	12.0	_	_	±100	_	±1000	nA	
(switch off)		V <sub>IN</sub> = V <sub>ILC</sub>								
Switch input leakage current		V <sub>OS</sub> =V <sub>CC</sub> or GND								
(switch on, output open)		V <sub>IN</sub> = V <sub>IHC</sub>	12.0	_	_	±100	_	±1000	nA	
		VIN - VIHC								
Control input current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	12.0	_	_	±100	_	±1000	nA	
Quiescent supply current	ly I <sub>CC</sub>		6.0	_	_	1.0	_	10.0		
		V <sub>IN</sub> = V <sub>CC</sub> or GND	9.0	_	_	4.0	_	40.0	μΑ	
			12.0	_	_	8.0	_	80.0		



AC Characteristics ( $C_L = 50 \text{ pF}$ , input:  $t_r = t_f = 6 \text{ ns}$ )

Characteristics	Symbol	Symbol Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
			VCC (V)	Min	Тур.	Max	Min	Max	
			2.0	_	10	50	_	65	ns
Phase difference between input and	<b>(0)</b> -		4.5	_	4	10	_	13	
output	ФІ-О	_	9.0	_	3	8	_	10	
			12.0	_	3	7	_	9	
			2.0	_	18	100	_	125	
Output anabla tima	$t_{pZL}$	D: = 1 k0	4.5	_	8	20	_	25	ns
Output enable time	t <sub>pZH</sub>	$R_L = 1 k\Omega$	9.0	_	6	12	_	22	IIS
			12.0	_	6	12	_	18	
	t <sub>pLZ</sub> t <sub>pHZ</sub>	R <sub>L</sub> = 1 kΩ	2.0	-	20	115	_	145	ns
Output disable time			4.5	_	10	23	_	29	
Output disable time			9.0	_	8	20	_	25	
			12.0	_	8	18	_	22	
		D. = 1 kO	2.0	_	30	_	_	_	MHz
Maximum control		$R_L = 1 \text{ k}\Omega$ $C_L = 15 \text{ pF}$	4.5	_	30	_	_	_	
input frequency			9.0	_	30	_	_	_	
		$V_{OUT}$ = 1/2 $V_{CC}$	12.0	_	30	_	_	_	
Control input capacitance	C <sub>IN</sub>	_		_	5	10	_	10	pF
Switch terminal capacitance	C <sub>I/O</sub>	_		_	6	_	_	_	pF
Feed through capacitance	C <sub>IOS</sub>	_		_	0.5	_	_	_	pF
Power dissipation capacitance	C <sub>PD</sub>		(Note)	_	15	_	_	_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 4 (per channel)$ 



# Analog Switch Characteristics (GND = 0 V, Ta = 25°C) (Note)

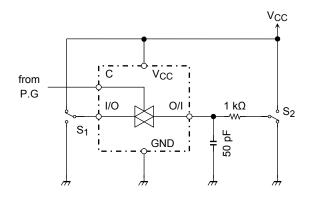
Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Sine wave distortion (T.H.D)		$f_{\text{IN}} = 1 \text{ kHz}, V_{\text{IN}} = 4 \text{ V}_{\text{p-p}}, @V_{\text{CC}} = 4.5 \text{ V}$ $R_{\text{L}} = 10 \text{ k}\Omega, V_{\text{IN}} = 8 \text{ V}_{\text{p-p}}, @V_{\text{CC}} = 9.0 \text{ V}$ $C_{\text{L}} = 50 \text{ pF}$	4.5 9.0	0.05 0.04	%
Frequency response (switch on)	f <sub>max</sub>	Adjust $f_{IN}$ voltage to obtain 0dBm at $V_{OS}$ Increase $f_{IN}$ frequency until dB meter reads $-3$ dB $R_L = 50~\Omega,~C_L = 10~pF$ $f_{IN} = 1~MHz$ , sine wave	4.5 9.0	200 200	MHz
Feedthrough attenuation (switch off)		Vin is centered at $V_{CC}/2$ Adjust input for 0dBm $R_L = 600 \ \Omega, \ C_L = 50 \ pF$ $f_{IN} = 1 \ MHz$ , sine wave	4.5 9.0	-60 -60	dB
Crosstalk (control input to signal output)		$R_L$ = 600 Ω, $C_L$ = 50 pF $f_{IN}$ = 1 MHz, square wave ( $t_r$ = $t_f$ = 6 ns)	4.5 9.0	60 100	mV
Crosstalk (between any switches)		Adjust $V_{IN}$ to obtain 0dBm at input R <sub>L</sub> = 600 $\Omega$ , C <sub>L</sub> = 50 pF $f_{IN}$ = 1 MHz, sine wave	4.5 9.0	-60 -60	dB

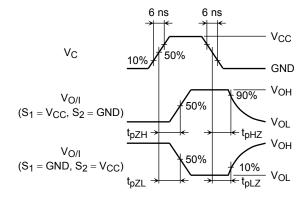
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Note: These characteristics are determined by design of devices.

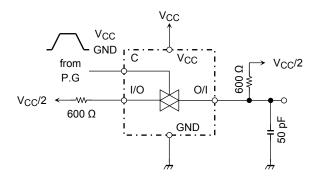
#### **Switching Characteristics Test Circuits**

## 1. $t_{pLZ}$ , $t_{pHZ}$ , $t_{pZL}$ , $t_{pZH}$

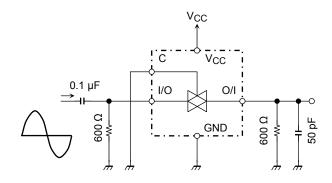




# 2. Cross Talk (control input-switch output) fIN = 1 MHz duty = 50% tr = tf = 6 ns

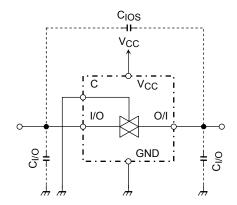


#### 3. Feedthrough Attenuation

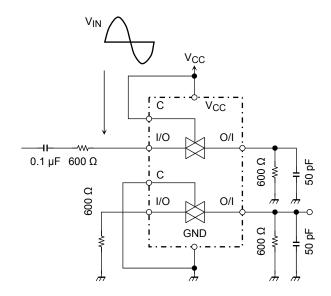




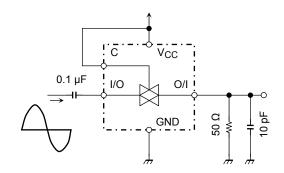
# 4. C<sub>IOS</sub>, C<sub>I/O</sub>



## 5. Crosstalk (between any two switches)

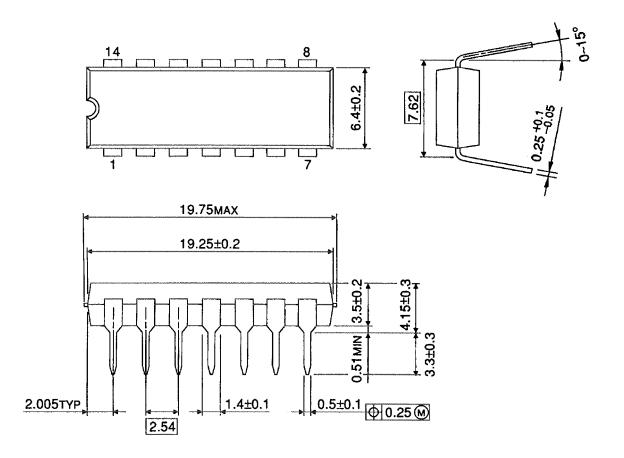


#### 6. Frequency Response (switch on)



# **Package Dimensions**

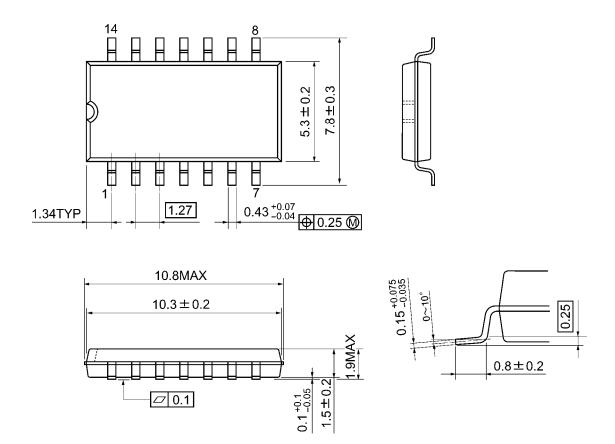
DIP14-P-300-2.54 Unit: mm



Weight: 0.96 g (typ.)

# **Package Dimensions**

SOP14-P-300-1.27A Unit: mm



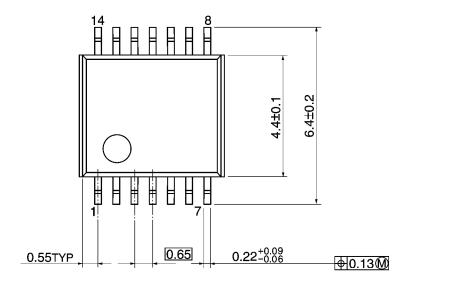
Weight: 0.18 g (typ.)

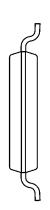


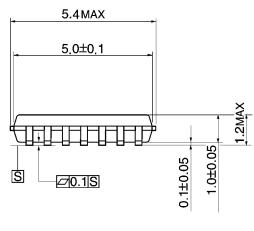
# **Package Dimensions**

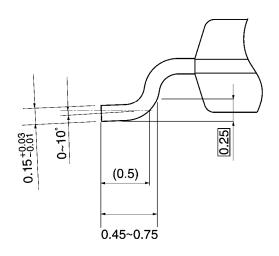
TSSOP14-P-0044-0.65A

Unit: mm









Weight: 0.06 g (typ.)

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